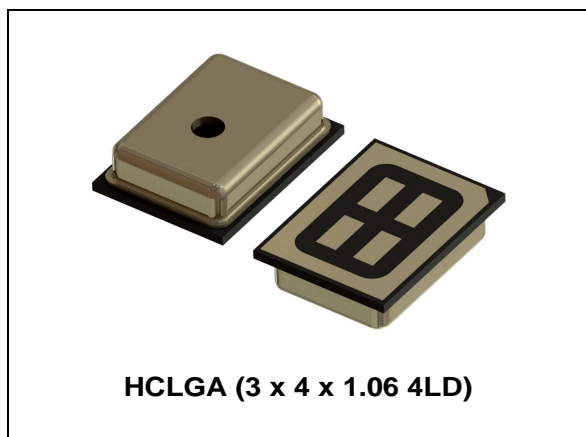


## MEMS audio sensor omnidirectional digital microphone

Datasheet - production data



### Features

- Single supply voltage
- Low power consumption
- 120 dB SPL acoustic overload point
- 61 dB signal-to-noise ratio
- Omnidirectional sensitivity
- – 26 dBFS sensitivity
- PDM output
- HCLGA package
  - Top-port design
  - SMD-compliant
  - EMI-shielded
  - ECOPACK®, RoHS, and “Green” compliant

- VoIP
- Speech recognition
- A/V eLearning devices
- Gaming and virtual reality input devices
- Digital still and video cameras
- Antitheft systems

### Description

The MP34DT01-M is an ultra-compact, low-power, omnidirectional, digital MEMS microphone built with a capacitive sensing element and an IC interface.

The sensing element, capable of detecting acoustic waves, is manufactured using a specialized silicon micromachining process dedicated to produce audio sensors.

The IC interface is manufactured using a CMOS process that allows designing a dedicated circuit able to provide a digital signal externally in PDM format.

The MP34DT01-M has an acoustic overload point of 120 dB SPL with a 61 dB signal-to-noise ratio and –26 dBFS sensitivity.

The MP34DT01-M is available in a top-port, SMD-compliant, EMI-shielded package and is guaranteed to operate over an extended temperature range from –40 °C to +85 °C.

### Applications

- Mobile terminals
- Laptop and notebook computers
- Portable media players

**Table 1. Device summary**

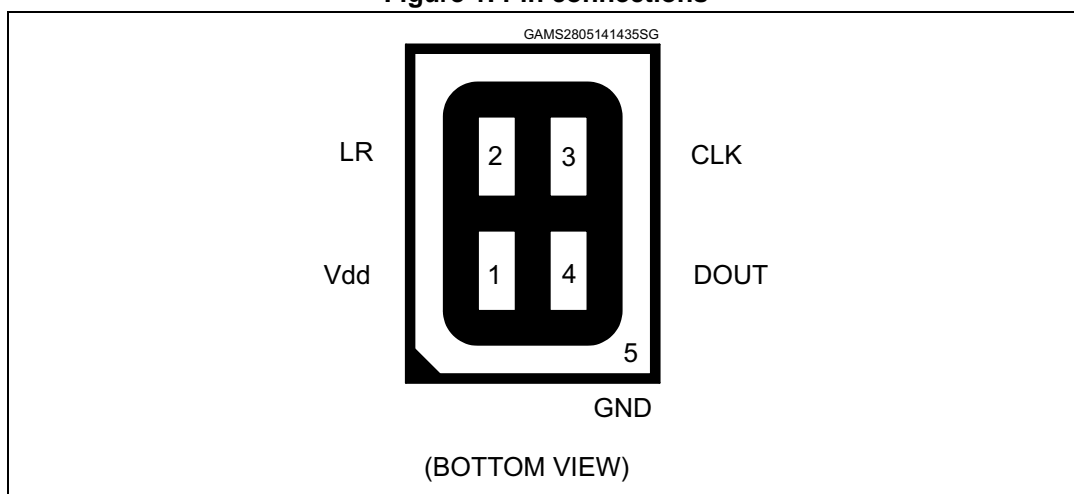
Order codes	Temperature range [°C]	Package	Packing
MP34DT01-M	–40 to +85	HCLGA (3 x 4 x 1.06) mm 4LD	Tray
MP34DT01TR-M			Tape and reel

# Contents

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# 1 Pin description

**Figure 1. Pin connections**



**Table 2. Pin description**

Pin #	Pin name	Function
1	Vdd	Power supply
2	LR	Left/Right channel selection
3	CLK	Synchronization input clock
4	DOUT	Left/Right PDM data output
5 (ground ring)	GND	0 V supply

## 2 Acoustic and electrical specifications

### 2.1 Acoustic and electrical characteristics

The values listed in the table below are specified for Vdd = 1.8 V, Clock = 2.4 MHz, T = 25 °C, unless otherwise noted.

**Table 3. Acoustic and electrical characteristics**

Symbol	Parameter	Test condition	Min.	Typ. <sup>(1)</sup>	Max.	Unit
Vdd	Supply voltage		1.64	1.8	3.6	V
Idd	Current consumption in normal mode	Mean value		0.6		mA
IddPdn	Current consumption in power-down mode <sup>(2)</sup>			20		μA
Sc	Short-circuit current		1		10	mA
AOP	Acoustic overload point			120		dB SPL
So	Sensitivity		-29	-26	-23	dB FS
SNR	Signal-to-noise ratio	A-weighted at 1 kHz, 1 Pa		61		dB
PSR	Power supply rejection	Guaranteed by design		-70		dB FS
Clock	Input clock frequency <sup>(3)</sup>		1	2.4	3.25	MHz
Ton	Turn-on time <sup>(4)</sup>	Guaranteed by design			10	ms
Top	Operating temperature range		-40		+85	°C
V <sub>IOL</sub>	Low level logic input/output voltage	I <sub>out</sub> = 1 mA	-0.3		0.35xVdd	V
V <sub>IOH</sub>	High level logic input/output voltage	I <sub>out</sub> = 1 mA	0.65xVdd		Vdd+0.3	V

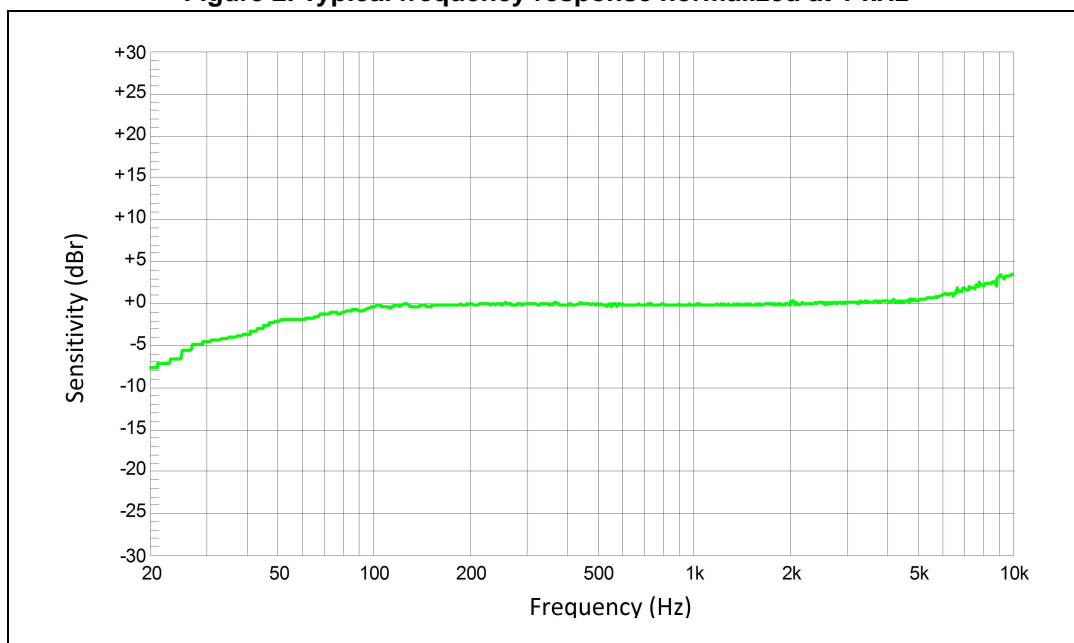
1. Typical specifications are not guaranteed.
2. Input clock in static mode.
3. Duty cycle: min = 40% max = 60%.
4. Time from the first clock edge to valid output data.

**Table 4. Distortion specifications**

Parameter	Test condition	Value
Distortion	100 dB SPL (1 kHz)	< 1% THD+N
Distortion	115 dB SPL (1 kHz)	< 2% THD+N
Distortion	120 dB SPL (1 kHz)	< 10% THD+N

## 2.2 Frequency response

Figure 2. Typical frequency response normalized at 1 kHz



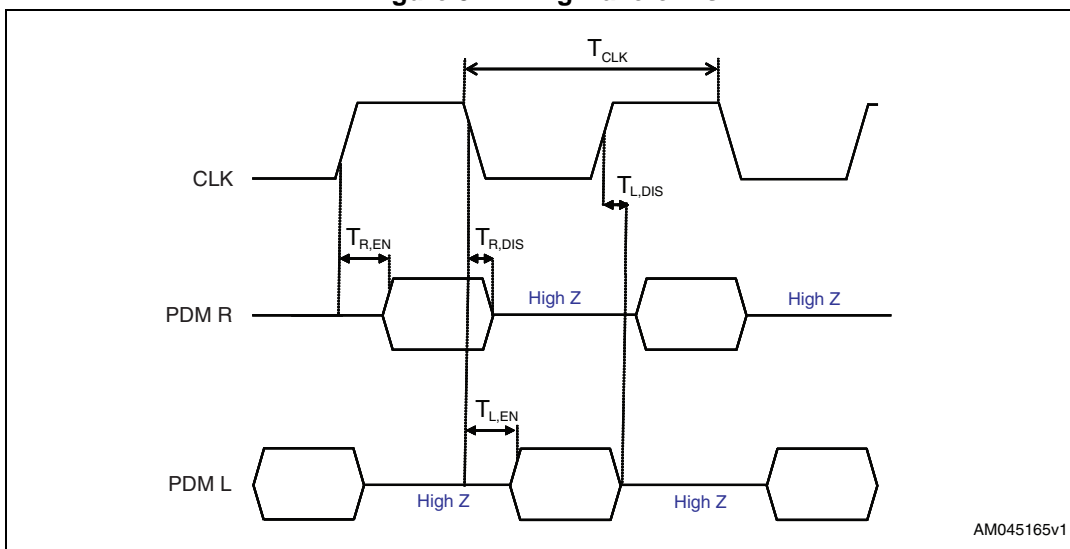
## 2.3 Timing characteristics

Table 5. Timing characteristics

Parameter	Description	Min.	Max.	Unit
$f_{CLK}$	Clock frequency for normal mode	1	3.25	MHz
$f_{PD}$	Clock frequency for power-down mode		0.23	MHz
$T_{CLK}$	Clock period for normal mode	308	1000	ns
$T_{R,EN}$	Data enabled on DATA line, L/R pin = 1	18 <sup>(1)</sup>		ns
$T_{R,DIS}$	Data disabled on DATA line, L/R pin = 1		16 <sup>(1)</sup>	ns
$T_{L,EN}$	Data enabled on DATA line, L/R pin = 0	18 <sup>(1)</sup>		ns
$T_{L,DIS}$	Data disabled on DATA line, L/R pin = 0		16 <sup>(1)</sup>	ns

1. From design simulations

Figure 3. Timing waveforms



### 3 Application recommendations

Figure 4. MP34DT01-M electrical connections (Top view)

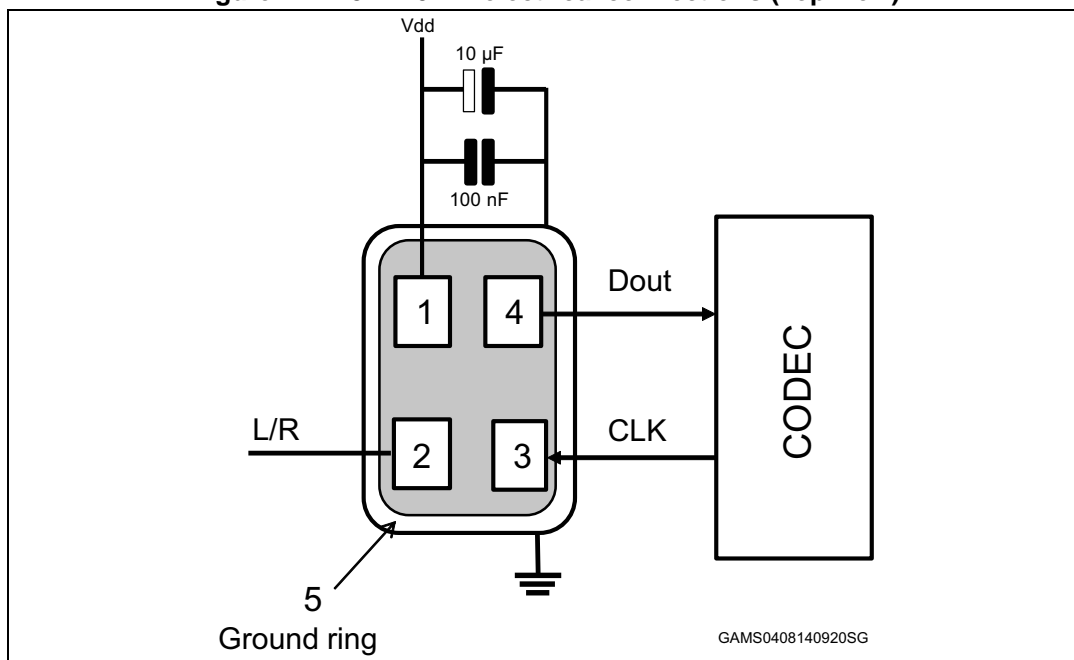
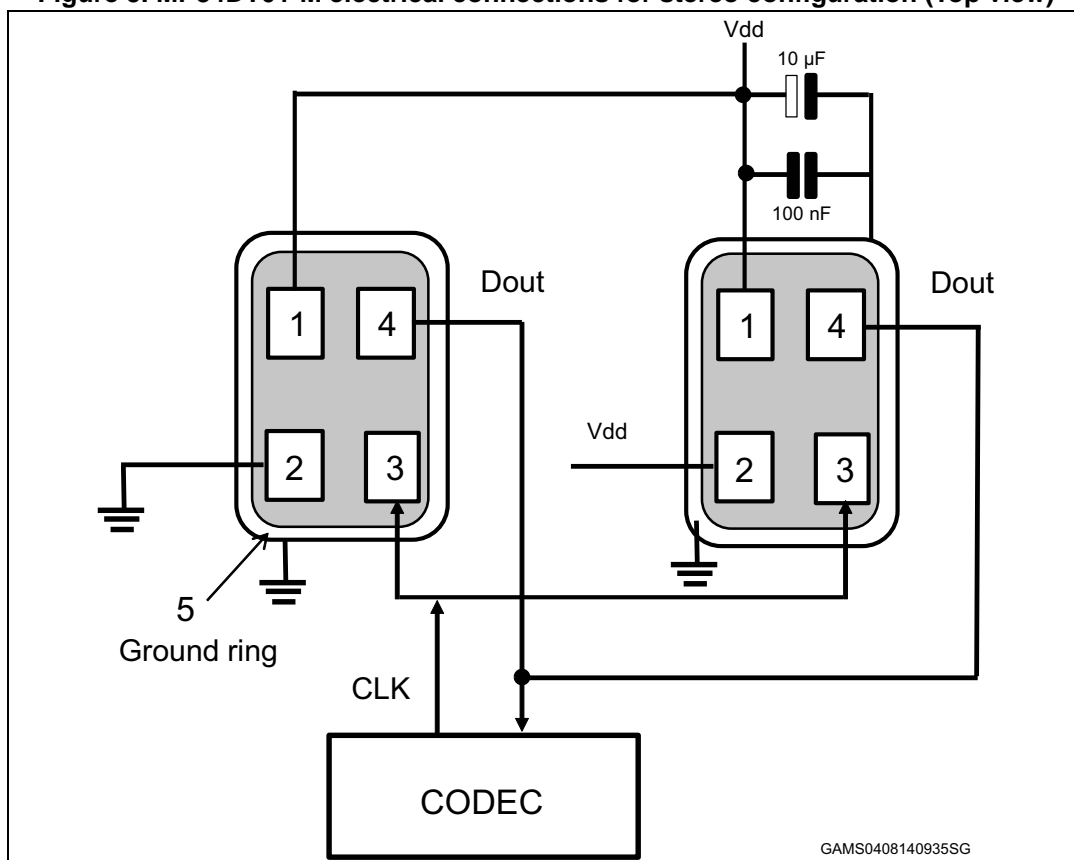


Figure 5. MP34DT01-M electrical connections for stereo configuration (Top view)



Power supply decoupling capacitors (100 nF ceramic, 10  $\mu$ F ceramic) should be placed as near as possible to pin 1 of the device (common design practice).

The L/R pin must be connected to Vdd or GND (refer to [Table 5](#)).



## 4 Sensing element

The sensing element shall mean the acoustic sensor consisting of a conductive movable plate and a fixed plate placed in a tiny silicon chip. This sensor transducers the sound pressure into the changes of coupled capacity between those two plates.

Omron Corporation supplies this element for STMicroelectronics.

## 5 Absolute maximum ratings

Stresses above those listed as “absolute maximum ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device under these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

**Table 6. Absolute maximum ratings**

Symbol	Ratings	Maximum value	Unit
V <sub>dd</sub>	Supply voltage	-0.3 to 6	V
V <sub>in</sub>	Input voltage on any control pin	-0.3 to V <sub>dd</sub> +0.3	V
T <sub>STG</sub>	Storage temperature range	-40 to +125	°C
ESD	Electrostatic discharge protection	2 (HBM)	kV
	3 discharges at ± 8 kV direct contact to lid when unit is grounded (IEC 61000-4-2) and 3 discharges at ± 2 kV direct contact to I/O pins. (MIL 883E, Method 3015.7)	± 8	kV



This device is sensitive to mechanical shock, improper handling can cause permanent damage to the part.



This device is ESD-sensitive, improper handling can cause permanent damage to the part.

## 6 Functionality

### 6.1 L/R channel selection

The L/R digital pad lets the user select the DOUT signal pattern as shown in [Table 7](#). The L/R pin must be connected to Vdd or GND.

**Table 7. L/R channel selection**

L/R	CLK low	CLK high
GND	Data valid	High impedance
Vdd	High impedance	Data valid

## 7 Package mechanical data

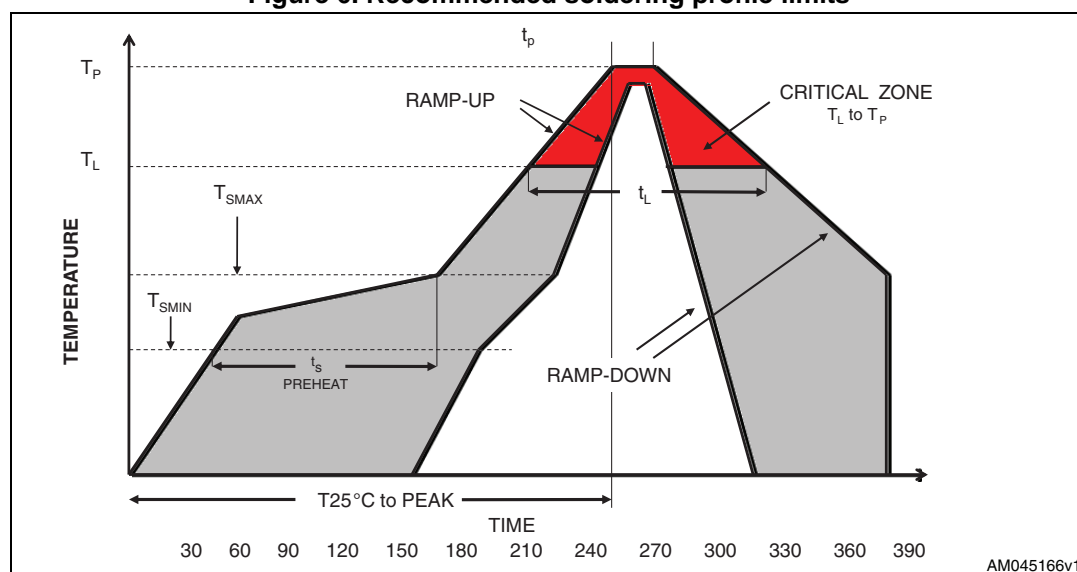
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### Soldering information

The HCLGA 3x4 4LD package is also compliant with the RoHS and “Green” standards and is qualified for soldering heat resistance according to JEDEC J-STD-020.

Landing pattern and soldering recommendations are available at [www.st.com](http://www.st.com).

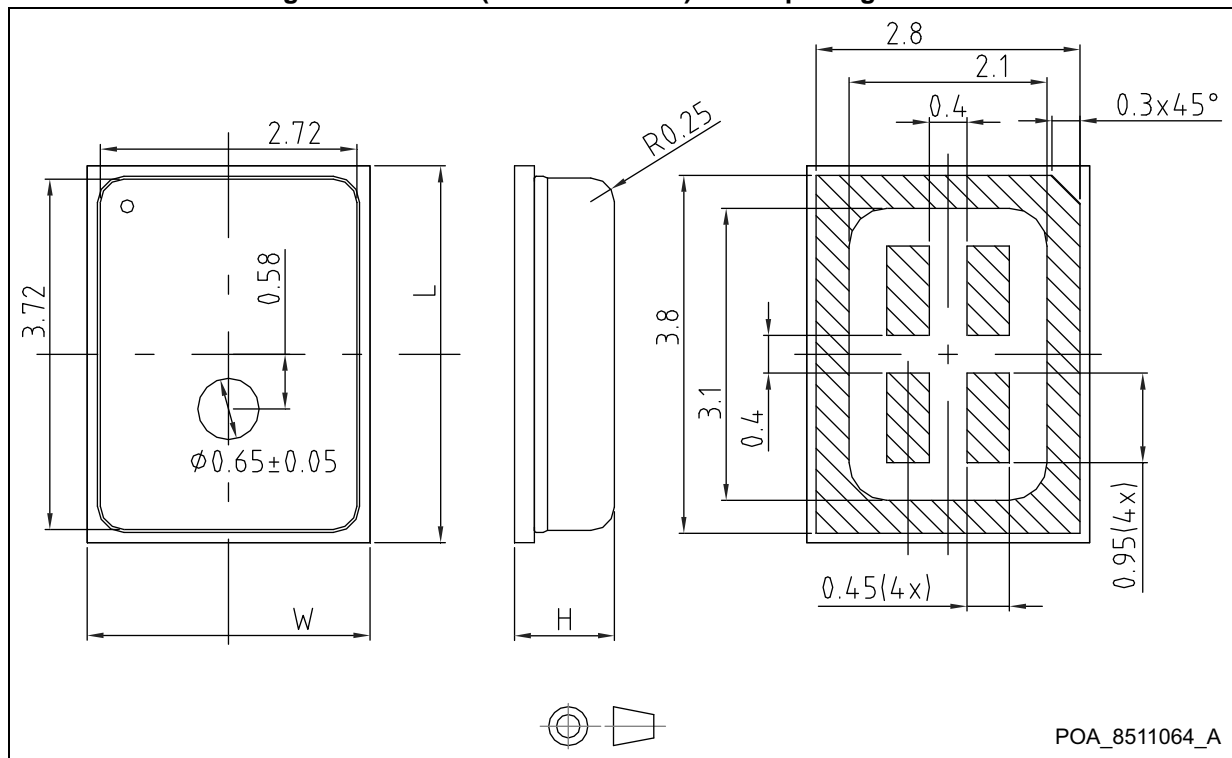
**Figure 6. Recommended soldering profile limits**



**Table 8. Recommended soldering profile limits**

Description	Parameter	Pb free
Average ramp rate	$T_L$ to $T_P$	3 °C/sec max
Preheat		
Minimum temperature	$T_{SMIN}$	150 °C
Maximum temperature	$T_{SMAX}$	200 °C
Time ( $T_{SMIN}$ to $T_{SMAX}$ )	$t_s$	60 sec to 120 sec
Ramp-up rate	$T_{SMAX}$ to $T_L$	
Time maintained above liquidus temperature	$t_L$	60 sec to 150 sec
Liquidus temperature	$T_L$	217 °C
Peak temperature	$T_P$	260 °C max
Time within 5 °C of actual peak temperature		20 sec to 40 sec
Ramp-down rate		6 °C/sec max
Time 25 °C ( $t_{25\text{ °C}}$ ) to peak temperature		8 minutes max

Figure 7. HCLGA (3 x 4 x 1.06 mm) 4-lead package outline



**Note:** The MEMS microphone metal cap can exhibit some level of variation in color when the device is subjected to thermal process.

Dimensions are in millimeter unless otherwise specified. General tolerance is  $\pm 0.15$  mm unless otherwise specified.

Table 9. HCLGA (3 x 4 x 1.06 mm) mechanical data

Item	Dimension (mm)	Tolerance (mm)
Length [L]	4	$\pm 0.1$
Width [W]	3	$\pm 0.1$
Height [H]	1.06	$\pm 0.1$

8 Carrier tape mechanical specifications

Figure 8. Carrier tape without microphone-top view

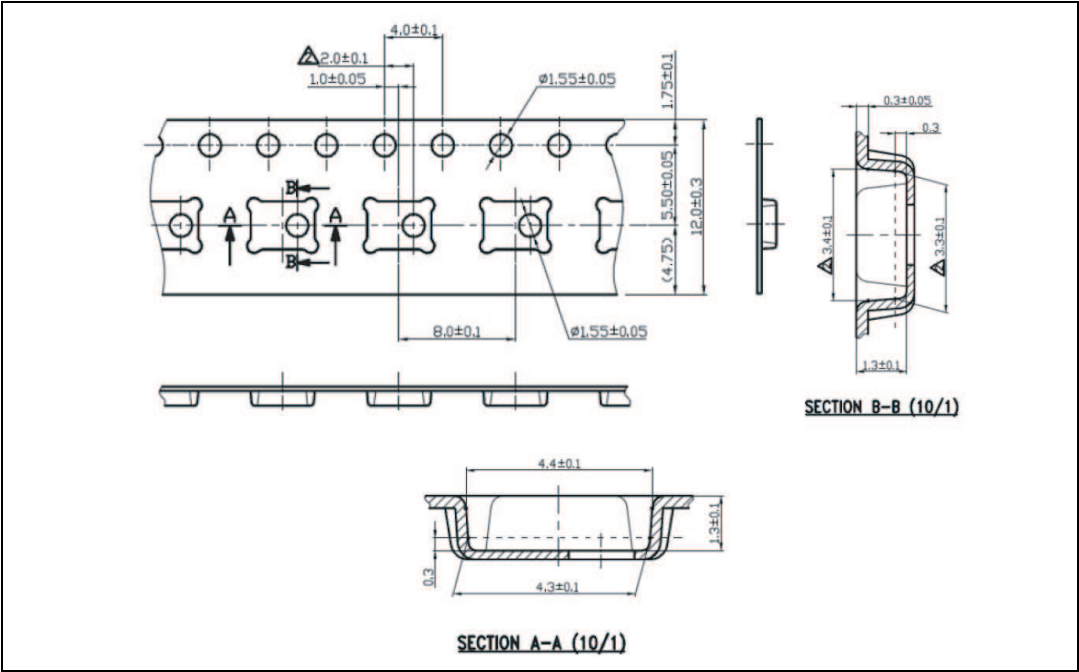
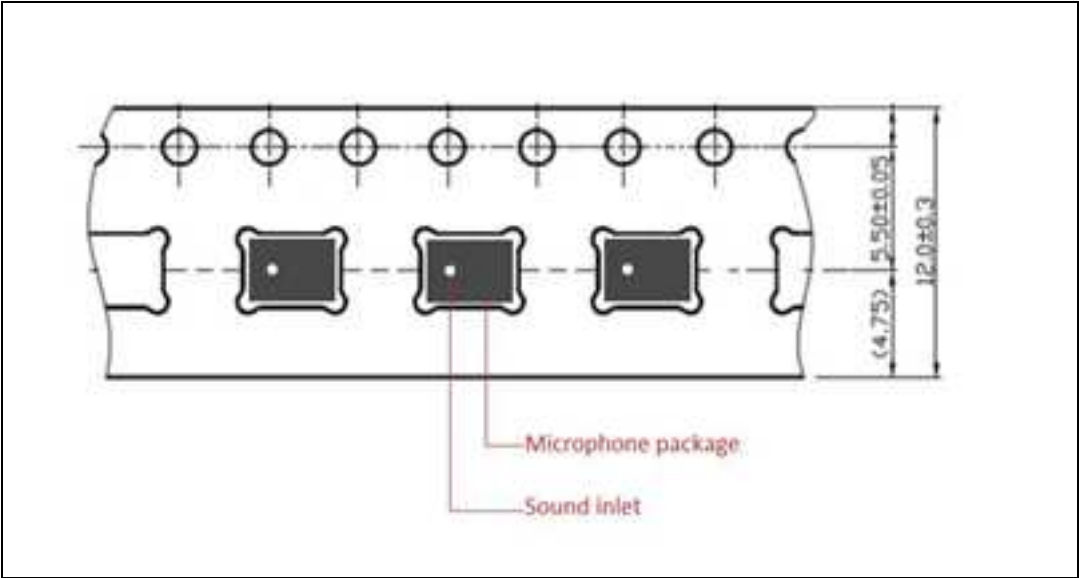


Figure 9. Carrier tape with microphone-top view

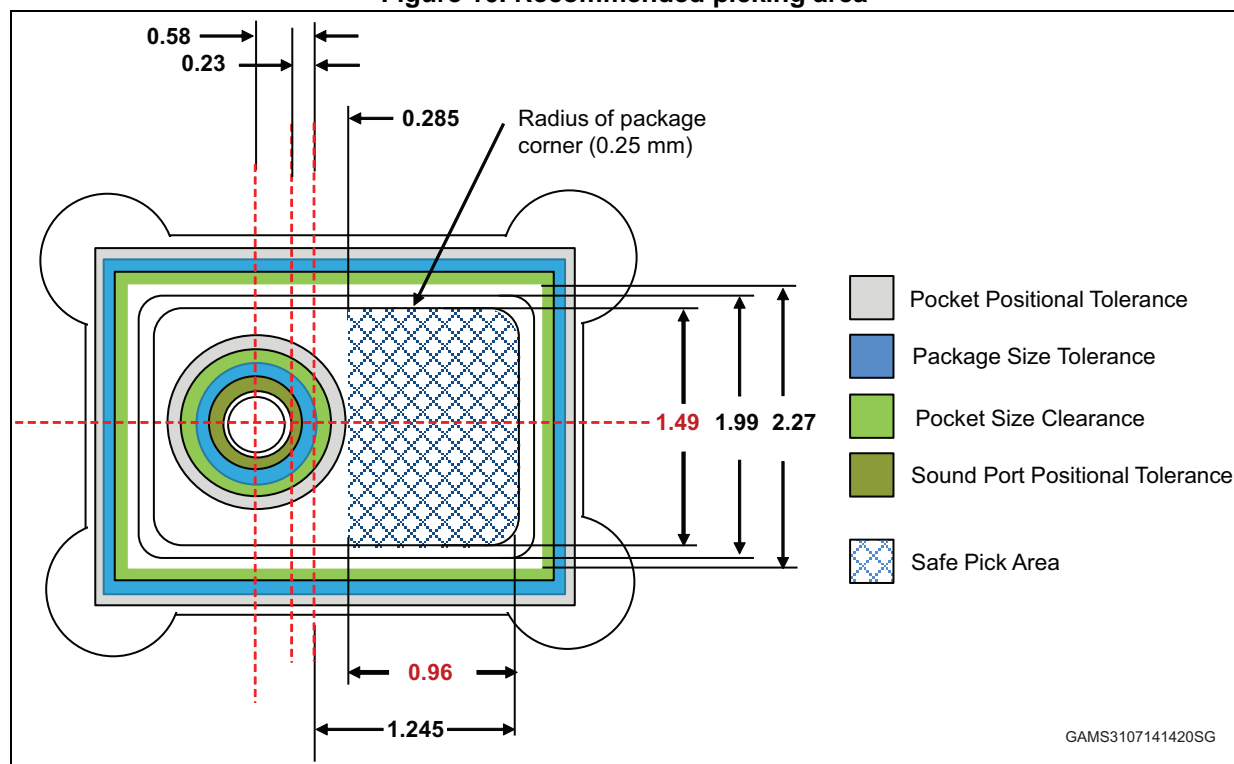


## 9 Process recommendations

To ensure a consistent manufacturing process it is strongly advised to comply with following recommendations:

- The recommended pick-up area for the MP34DT01-M package must be defined using the worst case (ie. no device alignment during picking process). This area has been defined considering all the tolerances of the components involved (reel, package, sound inlet). Picker tolerance shall be considered as well.
- To prevent damage to the MEMS membrane or incorrect pick-up and placement, do not pick up the component on the inlet area
- For the package outline please refer to [Figure 10](#). Nozzle shape, size, and placement accuracy are the other key factors to consider when deciding on the coordinates for the picking.
- Device alignment before picking is highly recommended.
- A vacuum force greater than 7 psi must be avoided
- $1 \text{ kPa} = 0.145 \text{ psi (lb/in}^2\text{)} = 0.0102 \text{ kgf/cm}^2 = 0.0098 \text{ atm}$
- All the recommended dimensions (device safe pick area) do not include the pick and place equipment tolerances
- According to [Figure 10](#), standard picker tool can be used to handle this device

**Figure 10. Recommended picking area**



## 10 Revision history

**Table 10. Document revision history**

Date	Revision	Changes
19-Jun-2014	1	Initial release
09-Jul-2014	2	Modified Min. and Max. values So parameter <a href="#">Table 3 on page 4</a>
03-Sep-2014	3	Added: <ul style="list-style-type: none"><li>– <a href="#">Table 4: Distortion specifications on page 4</a></li><li>– <a href="#">Section 3: Application recommendations on page 7</a></li><li>– <a href="#">Section 9: Process recommendations on page 15</a></li></ul>



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